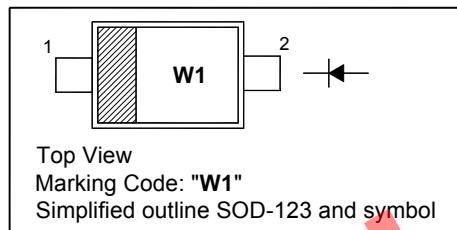


1N914W

Silicon Epitaxial Planar Switching Diode

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

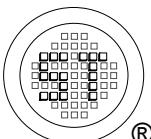


Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Reverse Voltage	V_{RRM}	100	V
Average Rectified Forward Current	$I_{F(AV)}$	215	mA
Non-repetitive Peak Forward Surge Current at $t = 1 \text{ s}$ at $t = 1 \mu\text{s}$	I_{FSM}	1 2	A
Power Dissipation	P_{tot}	400	mW
Thermal Resistance from Junction to Ambient Air	$R_{\theta JA}$	312	°C/W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	- 55 to + 150	°C

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 5 \mu\text{A}$ at $I_R = 100 \mu\text{A}$	$V_{(BR)R}$	75 100	- -	V
Forward Voltage at $I_F = 10 \text{ mA}$	V_F	-	1	V
Reverse Current at $V_R = 20 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 20 \text{ V}, T_j = 150^\circ\text{C}$	I_R	- - -	25 5 50	nA μA μA
Capacitance at $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	C_{tot}	-	4	pF
Reverse Recovery Time at $I_F = 10 \text{ mA}$ to $I_R = 1 \text{ mA}, V_R = 6 \text{ V}, R_L = 100 \Omega$	t_{rr}	-	4	ns



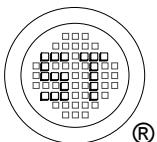
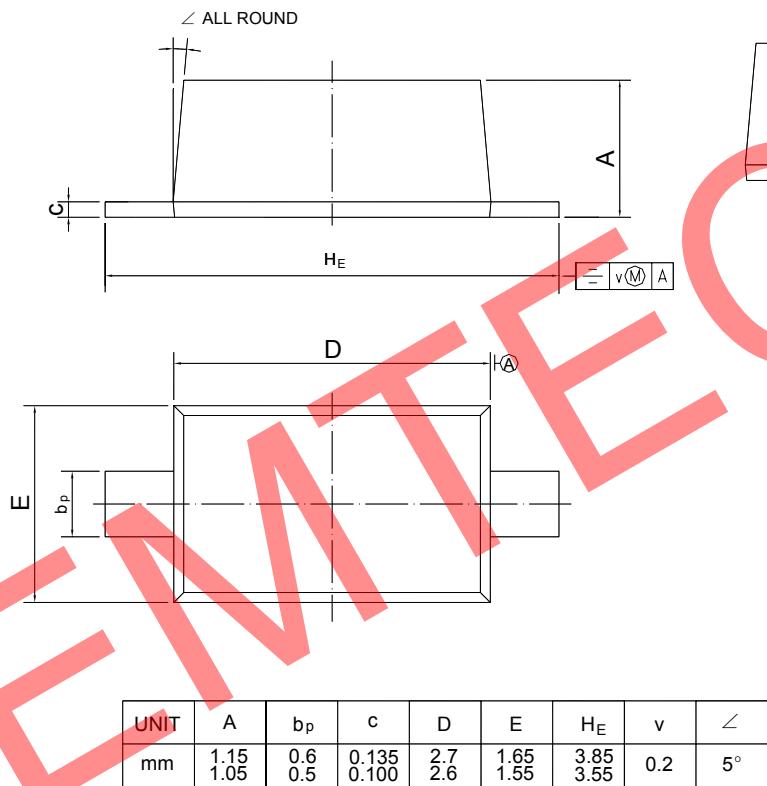
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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



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Dated: 01/08/2012 Rev: 02